

BSZ075N08NS5ATMA1

BSZ075N08NS5ATMA1 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



Request a Quote

BSZ075N08NS5ATMA1 Specifications

Manufacturer Part Number	BSZ075N08NS5ATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	80V
Current - Continuous Drain (Id) @ 25°C	40A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3.8V @ 36µA
Gate Charge (Qg) (Max) @ Vgs	29.5nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2080pF @ 40V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	69W (Tc)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 20A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TSDSON-8-FL
Package / Case	8-PowerTDFN
	Report errors?

BSZ075N08NS5ATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

BSZ075N08NS5ATMA1 Payment Methods



BSZ075N08NS5ATMA1 Shipping Methods



If you have any question about BSZ075N08NS5ATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com